



# Nanoantenna-Enabled Midwave Infrared Detection

David W. Peters, Darin Leonhardt, Charles Reinke, Jin K. Kim, Paul Davids, Joel Wendt, John Klem  
dwpeter@sandia.gov

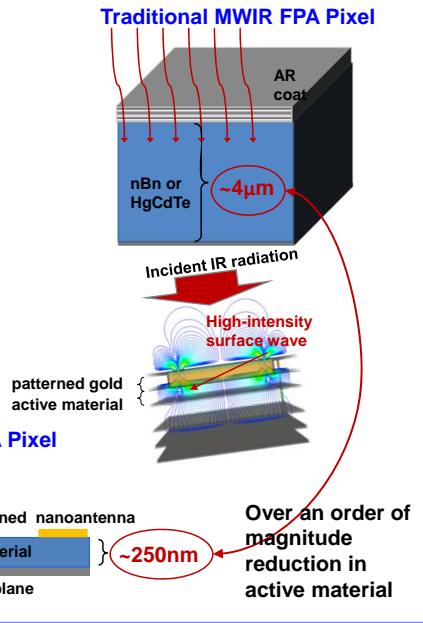
SAND2013-3539C

## Concept

In a traditional pixel the active layer must be thick enough to absorb the incoming radiation.

The nanoantenna converts plane waves to highly concentrated surface waves.

This allows the active layer to be made much thinner than in the traditional pixel architecture.



Advantages for near-IR, MWIR, and LWIR Focal Plane Arrays →  
Performance Improvements and Design Flexibility Independent of Active Material

### What does thin buy you?



Volume of active material (MCT or nBn) required goes down by over an order of magnitude.

Less material → lower dark current → better performance at a fixed temperature or equal performance at a higher temperature (less cooling required).

Thin layer allows more freedom with strain of the material. In the case of nBn, we can push the **cutoff wavelength** higher by tenths of microns.

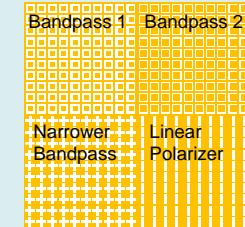
Thinner layer means less dead area between pixels used for reduction of **crosstalk**, and leading to **better modulation transfer function (MTF)** → higher resolution.

Less material deposition = easier fab/higher yield/fewer dead pixels. Should lead to lower cost detectors.

### Incorporate optical features at pixel level:

We have made bandpass filtering and polarizing nanoantennas → we can integrate filtering functionality on the detector itself.

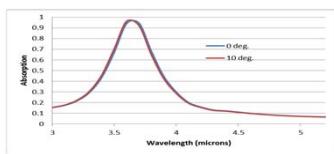
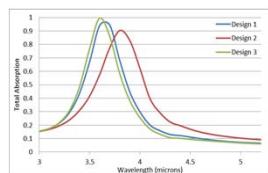
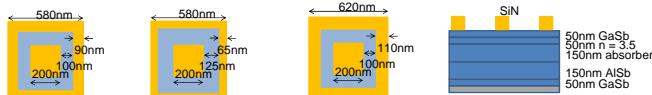
Our active material is broadband, allowing two-color FPAs. AR coat may be changed pixel to pixel.



## Optical Modeling

Shows where the absorption occurs.

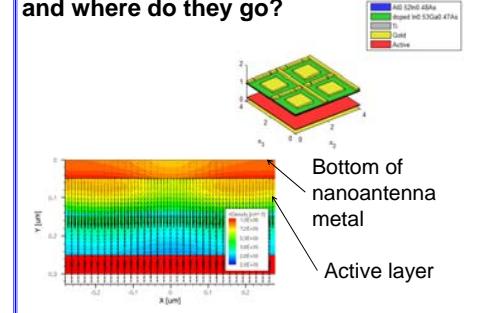
Optimize designs for largest absorption in active region.  
RCWA, FDTD, and FEM modeling.



Nanoantenna spectral band is usually independent of angle.

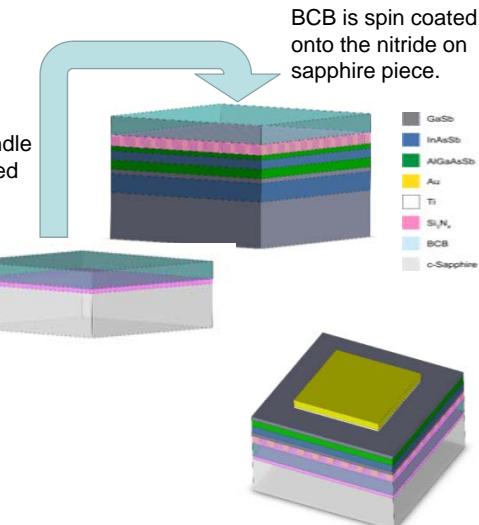
## Electrical Modeling

Where are the carriers generated and where do they go?

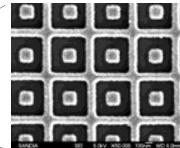
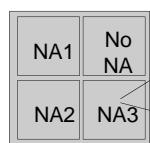


## Fabrication

- Epitaxial layers are grown on GaSb.
- Nanoantenna is fabbed using metal liftoff process.
- Wafer is bonded to a sapphire handle wafer and the GaSb removed.
- Detector connections made.



The three nanoantenna designs are patterned on the same stack plus a no nanoantenna control.



## ACKNOWLEDGEMENT

Sandia National Laboratories is a multi-program laboratory managed and operated by Sandia Corporation, a wholly owned subsidiary of Lockheed Martin Corporation, for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000.